



20V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	38mΩ @ V _{GS} = 4.5V	4.0A
20V	45mΩ @ V _{GS} = 2.5V	3.7A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Battery Charging
- Power Management Functions
- DC-DC Converters
- Portable Power Adaptors

Features and Benefits

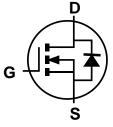
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

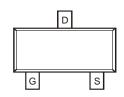
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (§3)
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)







Internal Schematic



Top View

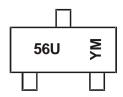
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2056U-7	SOT23	3000/Tape & Reel
DMN2056U-13	SOT23	10000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



56U = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: D = 2016) M = Month (ex: 9 = September)

Date Code Key

Date Code Ney												
Year	2016		2017	2018		2019	2020		2021	2022	!	2023
Code	D		E	F		G	Н		I	J		K
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V_{DSS}	20	V
Gate-Source Voltage	V_{GSS}	±8	V
Continuous Drain Current (Note 6) V _{GS} = 4.5V	Ι _D	4.0 3.2	А
Maximum Body Diode Forward Current (Note 6)	Is	1.0	Α
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	22	A

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)		P_{D}	0.66	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta JA}$	192	°C/W
Power Dissipation (Note 6)		P_{D}	0.94	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	136	°C/W
Operating and Storage Temperature Range		$T_{J_i} T_{STG}$	-55 to +150	°C

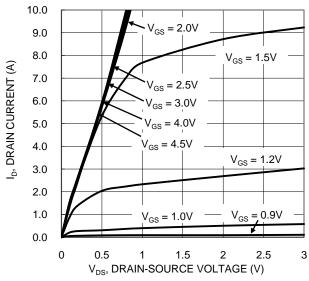
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)								
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$		
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 20V, V_{GS} = 0V$		
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 8V$, $V_{DS} = 0V$		
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage	V _{GS(TH)}	0.4	0.6	1.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$		
		_	30	38		$V_{GS} = 4.5V, I_D = 3.6A$		
Static Drain-Source On-Resistance	R _{DS(ON)}	_	34	45	mΩ	V _{GS} = 2.5V, I _D = 3.1A		
	, ,	_	52	85		V _{GS} = 1.5V, I _D = 2.0A		
Diode Forward Voltage	V _{SD}	_	0.7	1.2	V	V _{GS} = 0V, I _S = 1A		
DYNAMIC CHARACTERISTICS (Note 8)								
Input Capacitance	Ciss		339	_		V _{DS} = 10V, V _{GS} = 0V f = 1.0MHz		
Output Capacitance	Coss	_	47	_	pF			
Reverse Transfer Capacitance	Crss		34	_		1 = 1.0IVII IZ		
Gate Resistance	R_{G}	_	2.6	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$		
Total Gate Charge	Qq	_	4.3	_				
Gate-Source Charge	Q_{gs}	_	0.5	_	nC	$V_{DS} = 10V, V_{GS} = 4.5V, I_{D} = 3.6A$		
Gate-Drain Charge	Q_{gd}	_	8.0	_				
Turn-On Delay Time	t _{D(ON)}	_	1.8	_				
Turn-On Rise Time	t _R	_	2.8	_		$V_{GS} = 4.5V$, $V_{DD} = 10V$, $R_{G} = 1\Omega$,		
Turn-Off Delay Time	t _{D(OFF)}	_	8.5	_	ns	$I_D = 3.6A$		
Turn-Off Fall Time	t _F	_	1.7					
Body Diode Reverse Recovery Time	t _{RR}	_	4.7	_	ns	I _F = 3.6A, dl/dt = 100A/μs		
Body Diode Reverse Recovery Charge	Q _{RR}		0.7		nC	I _F = 3.6A, dl/dt = 100A/µs		

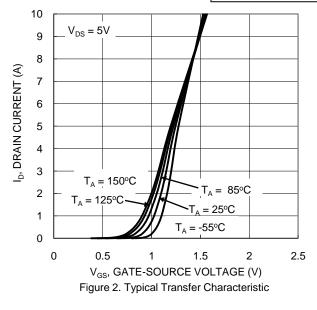
Notes:

- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1 inch square copper plate.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.









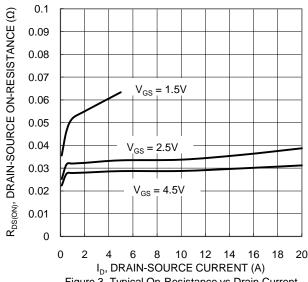
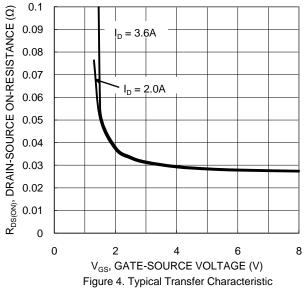


Figure 3. Typical On-Resistance vs Drain Current and Gate Voltage



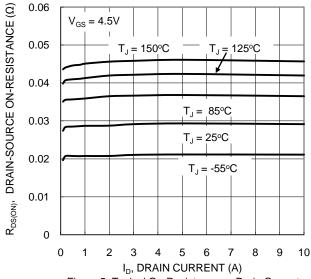


Figure 5. Typical On-Resistance vs Drain Current and Junction Temperature

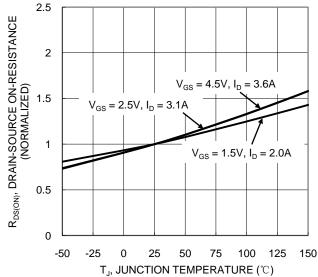
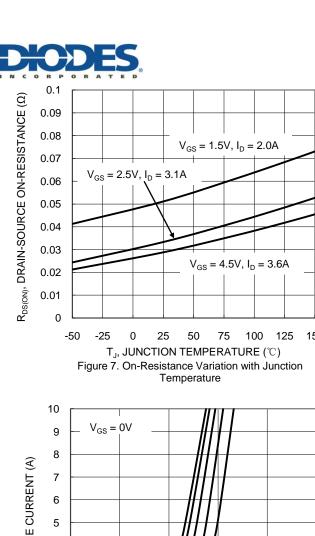
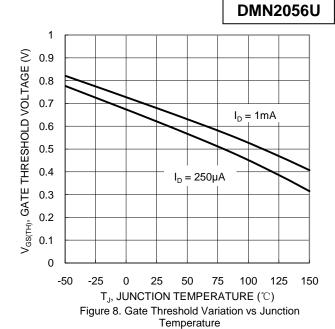
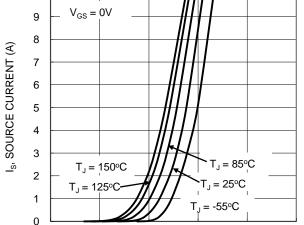


Figure 6. On-Resistance Variation with Junction Temperature







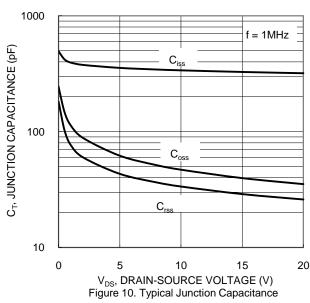
0.6

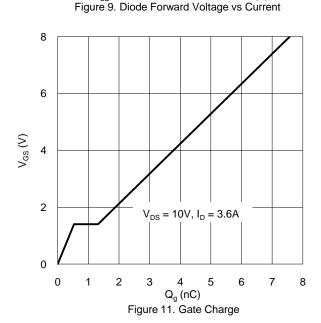
0.9

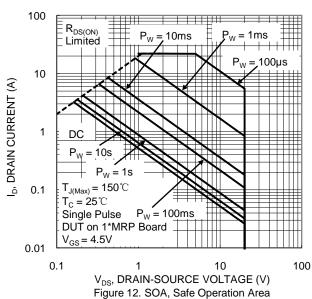
 V_{SD} , SOURCE-DRAIN VOLTAGE (V)

1.2

1.5





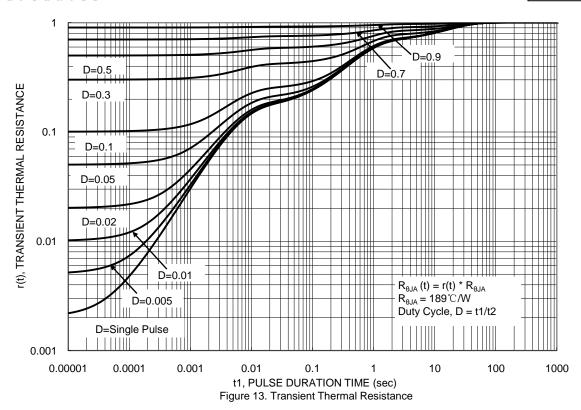


0

0.3

June 2016



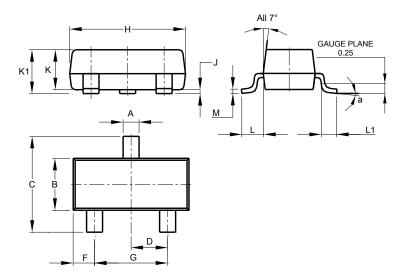




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

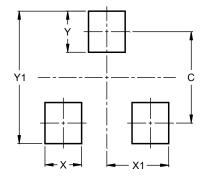


SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
H	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)			
C	2.0			
Х	0.8			
X1	1.35			
Y	0.9			
Y1	2.9			



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